TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM6N05FU

High Speed Switching Applications

- Small package
- Low on resistance : $R_{on} = 0.8 \Omega (max) (@V_{GS} = 4 V)$

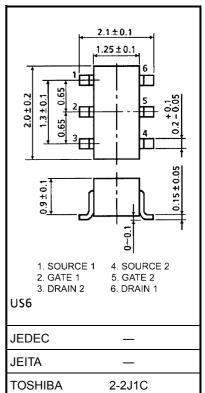
: $R_{on} = 1.2 \Omega (max) (@V_{GS} = 2.5 V)$

• Low gate threshold voltage

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	20	V	
Gate-Source voltage		V _{GSS}	±12	V	
Drain current	DC	۱ _D	400	mA	
	Pulse	I _{DP}	800		
Drain power dissipation (Ta = 25° C)		P _D (Note1)	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.32 mm $^2 \times$ 6)



Weight: 6.8 mg (typ.)

Handling Precaution

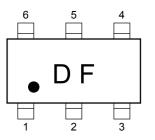
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

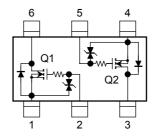
Unit: mm

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Marking







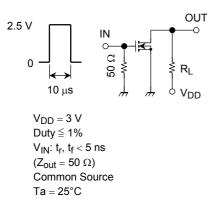
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 12~V,~V_{DS}=0$	_		±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	20	_		V
Drain cut-off current		I _{DSS}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0$	_	_	1	μA
Gate threshold voltage		V _{th}	$V_{DS} = 3 V, I_D = 0.1 mA$	0.6	_	1.1	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 V, I_D = 200 mA$ (Note2)	350	_	_	mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = 200 \text{ mA}, V_{GS} = 4 \text{ V} \qquad (\text{Note2})$	_	0.6	0.8	Ω
			$I_D = 200 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note2)	_	0.85	1.2	
Input capacitance		C _{iss}			22	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V$, $V_{GS} = 0$, f = 1 MHz		9	_	pF
Output capacitance		C _{oss}			21	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 V, I_D = 100 mA,$		60	_	ns
	Turn-off time	t _{off}	$V_{GS} = 0 \sim 2.5 V$	_	70		

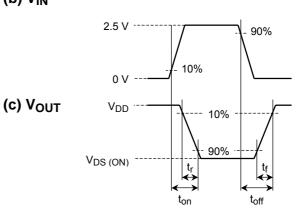
Note2: Pulse test

Switching Time Test Circuit

(a) Test circuit



(b) V_{IN}

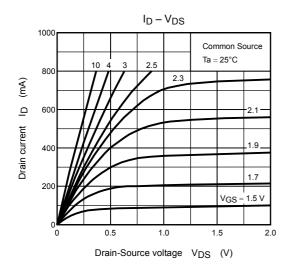


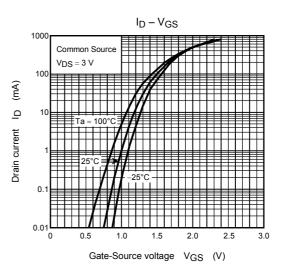
Precaution

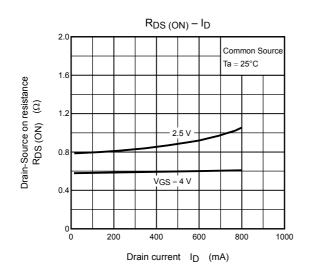
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (_on) requires higher voltage than V_{th} and V_{GS} (_off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (_off) < V_{th} < V_{GS} (_on))

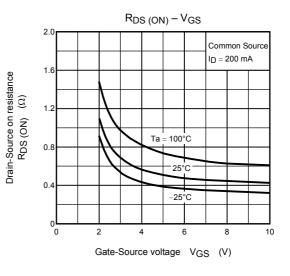
Please take this into consideration for using the device. V_{GS} recommended voltage of 2.5 V or higher to turn on this product.

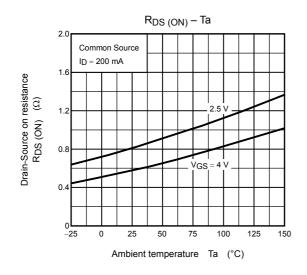
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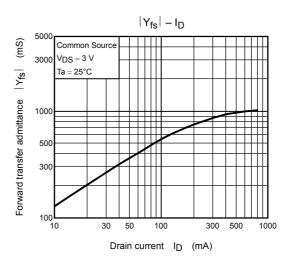






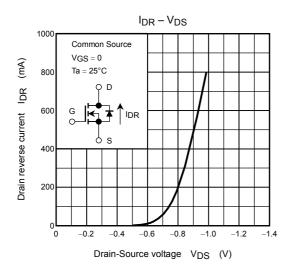


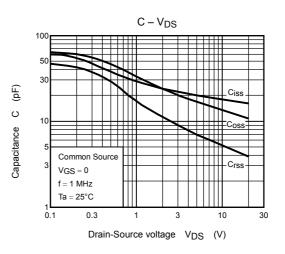


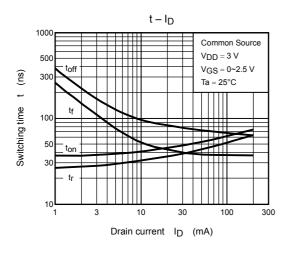


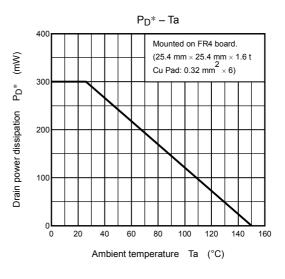
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(Q1, Q2 common)









*: Total rating

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